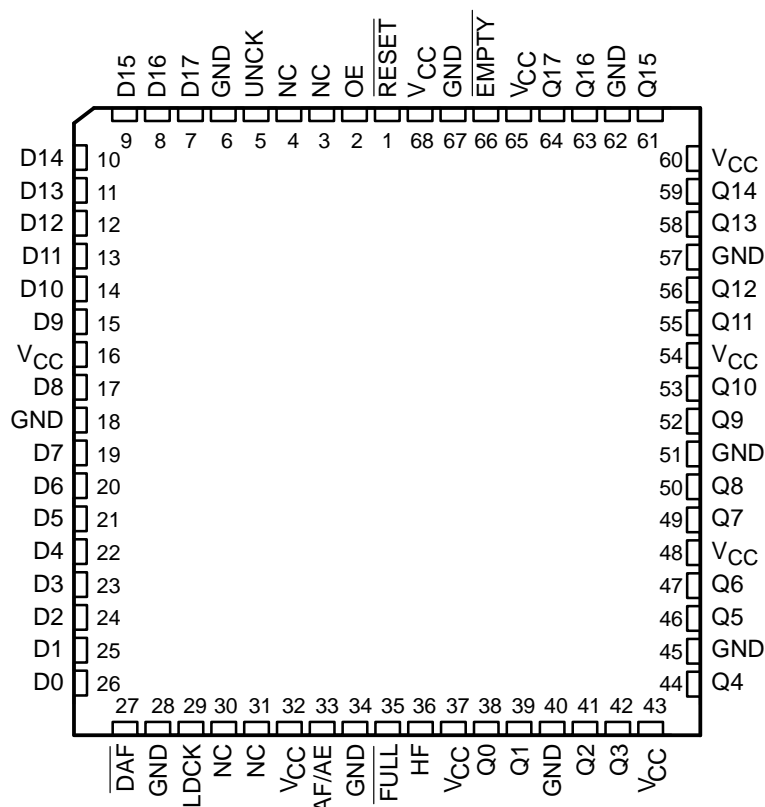


STROBED FIRST-IN, FIRST-OUT MEMORY

SCAS187B – AUGUST 1990 – REVISED SEPTEMBER 1995

- Load and Unload Clocks Can Be Asynchronous or Coincident
- Low-Power Advanced CMOS Technology
- 1024 Words × 18 Bits
- Programmable Almost-Full/Almost-Empty Flag
- Empty, Full, and Half-Full Flags
- Fast Access Times of 30 ns With a 50-pF Load
- Fall-Through Time Is 20 ns Typical
- Data Rates From 0 to 40 MHz
- High-Output Drive for Direct Bus Interface
- 3-State Outputs
- Available in 68-Pin PLCC (FN) and 80-Pin Thin Quad Flat (PN) Packages

FN PACKAGE
(TOP VIEW)

NC – No internal connection



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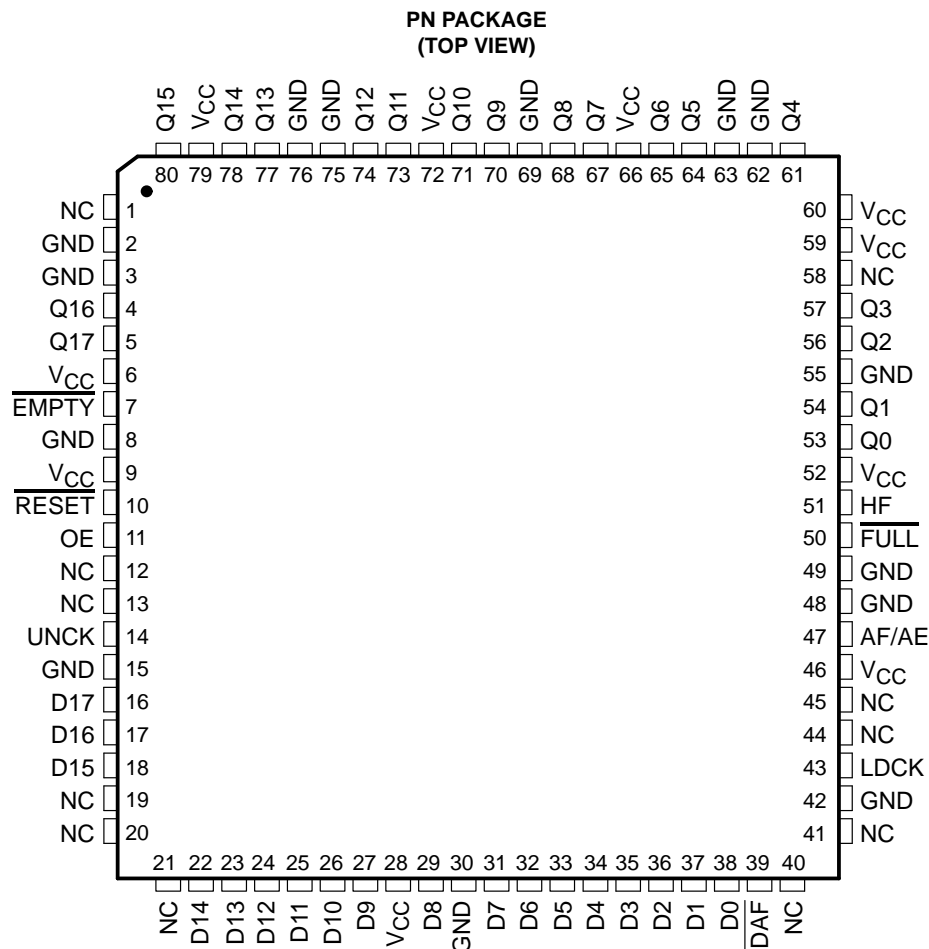
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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SN74ACT7802
1024 × 18
STROBED FIRST-IN, FIRST-OUT MEMORY
 SCAS187B – AUGUST 1990 – REVISED SEPTEMBER 1995



NC – No internal connection

description

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. The SN74ACT7802 is a 1024-word by 18-bit FIFO for high-speed applications. It processes data in a bit-parallel format at rates up to 40 MHz and access times of 30 ns.

Data is written into the FIFO memory on a low-to-high transition on the load-clock (LDCK) input and is read out on a low-to-high transition on the unload-clock (UNCK) input. The memory is full when the number of words clocked in exceeds by 1024 the number of words clocked out. When the memory is full, LDCK has no effect on the data in the memory; when the memory is empty, UNCK has no effect.

A low level on the reset ($\overline{\text{RESET}}$) input resets the FIFO internal clock stack pointers and sets $\overline{\text{FULL}}$ high, AF/AE high, HF low, and $\overline{\text{EMPTY}}$ low. The Q outputs are not reset to any specific logic level. The FIFO must be reset upon power up. The Q outputs are noninverting and are in the high-impedance state when the output-enable (OE) input is low.

When writing to the FIFO after a reset pulse or when the FIFO is empty, the first active transition on LDCK drives $\overline{\text{EMPTY}}$ high and causes the first word written to the FIFO to appear on the Q outputs. An active transition on UNCK is not required to read the first word written to the FIFO. Each subsequent read from the FIFO requires an active transition on UNCK.

The SN74ACT7802 can be cascaded in the word-width direction but not in the word-depth direction.

The SN74ACT7802 is characterized for operation from 0°C to 70°C.

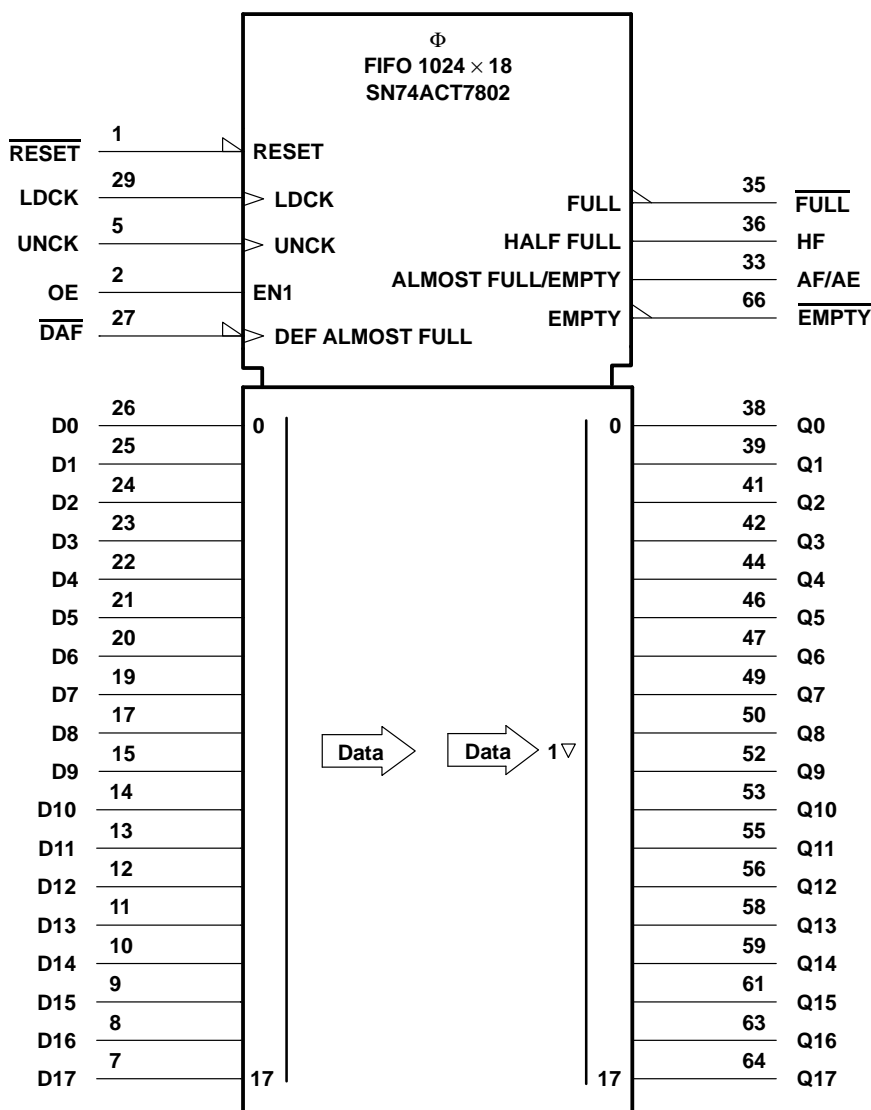


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STROBED FIRST-IN, FIRST-OUT MEMORY

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logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for the FN package.

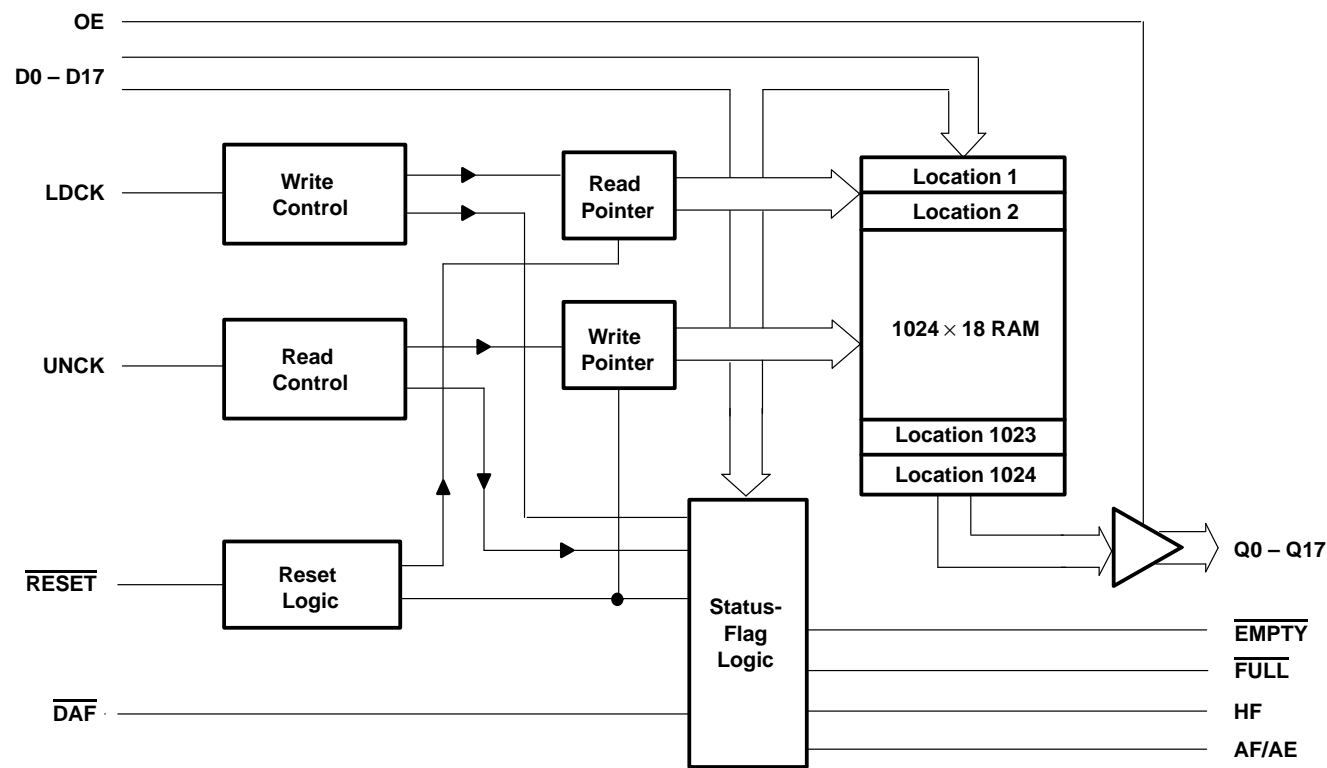
SN74ACT7802

1024 × 18

STROBED FIRST-IN, FIRST-OUT MEMORY

SCAS187B – AUGUST 1990 – REVISED SEPTEMBER 1995

functional block diagram



Terminal Functions

TERMINAL NAME	NO.†	I/O	DESCRIPTION
AF/AE	33	O	Almost-full/almost-empty flag. Depth-offset values can be programmed for AF/AE, or the default value of 256 can be used for the almost-empty almost-full offset (X). AF/AE is high when memory contains X or less words or (1024 – X) or more words. AF/AE is high after reset.
$\overline{\text{DAF}}$	27	I	Define almost full flag. The high-to-low transition of $\overline{\text{DAF}}$ stores the binary value of data inputs as the almost-full/almost-empty offset value (X). With DAF held low, a low pulse on RESET defines AF/AE using X.
D0–D17	7–15, 17, 19–26	I	18-bit data input port
$\overline{\text{EMPTY}}$	66	O	Empty flag. $\overline{\text{EMPTY}}$ is low when the FIFO is empty. A FIFO reset also causes $\overline{\text{EMPTY}}$ to go low.
$\overline{\text{FULL}}$	35	O	Full flag. $\overline{\text{FULL}}$ is low when the FIFO is full. A FIFO reset causes $\overline{\text{FULL}}$ to go high.
HF	36	O	Half-full flag. HF is high when the FIFO memory contains 512 or more words. HF is low after reset.
LDCK	29	I	Load clock. Data is written to the FIFO on the rising edge of LDCK when $\overline{\text{FULL}}$ is high.
OE	2	I	Output enable. When OE is low, the data outputs are in the high-impedance state.
Q0–Q17	38–39, 41–42, 44, 46–47, 49–50, 52–53, 55–56, 58–59, 61, 63–64	O	18-bit data output port
$\overline{\text{RESET}}$	1	I	Reset. A low level on $\overline{\text{RESET}}$ resets the FIFO and drives AF/AE and $\overline{\text{FULL}}$ high and HF and $\overline{\text{EMPTY}}$ low.
UNCK	5	I	Unload clock. Data is read from the FIFO on the rising edge of UNCK when $\overline{\text{EMPTY}}$ is high.

† Pin numbers shown are for the FN package.

offset value values for AF/AE

The FIFO memory status is monitored by the full ($\overline{\text{FULL}}$), empty ($\overline{\text{EMPTY}}$), half-full (HF), and almost-full/almost-empty (AF/AE) flags. The $\overline{\text{FULL}}$ output is low when the memory is full; the $\overline{\text{EMPTY}}$ output is low when the memory is empty. The HF output is high when the memory contains 512 or more words and low when it contains less than 512 words. The level of the AF/AE flag is determined by both the number of words in the FIFO and a user-definable offset X. AF/AE is high when the FIFO is almost full or almost empty, i.e., when it contains X or less words or $(1024 - X)$ or more words. The almost-full/almost-empty offset value is either user-defined or the default value of 256; it is programmed during each reset cycle as follows:

user-defined X:

Take $\overline{\text{DAF}}$ from high to low.

If $\overline{\text{RESET}}$ is not already low, take $\overline{\text{RESET}}$ low.

With $\overline{\text{DAF}}$ held low, take $\overline{\text{RESET}}$ high. This defines the AF/AE flag using X.

default X:

To redefine the AF/AE flag using the default value of $X = 256$, hold $\overline{\text{DAF}}$ high during the reset cycle.

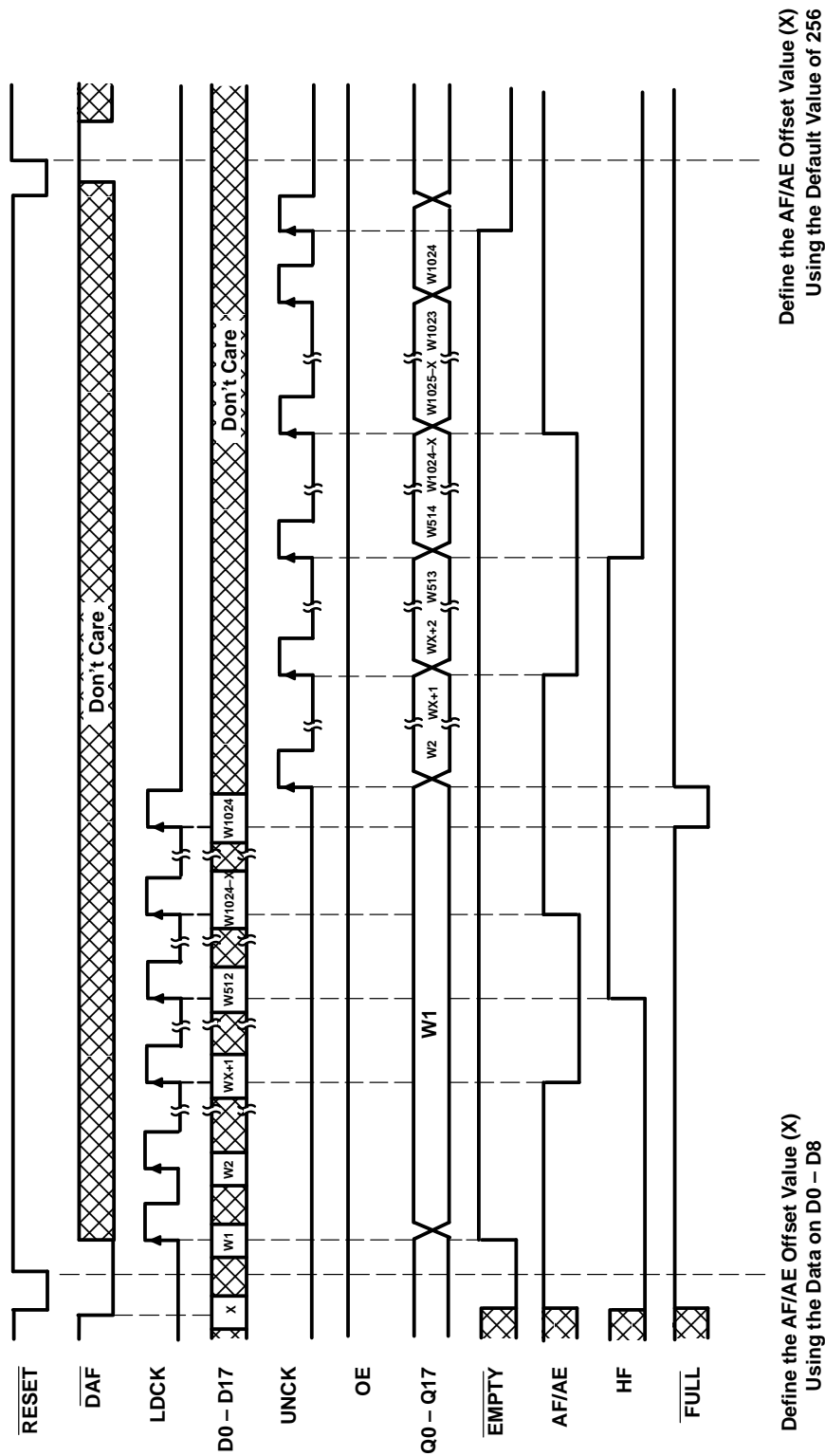


Figure 2. Write, Read, and Flag Timing Reference

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage, V_I	7 V
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range, T_A	0°C to 70°C
Storage temperature range, T_{stg}	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		'ACT7802-25		'ACT7802-40		'ACT7802-60		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage	4.5	5.5	4.5	5.5	4.5	5.5	V
V _{IH}	High-level input voltage	2		2		2		V
V _{IL}	Low-level input voltage		0.8		0.8		0.8	V
I _{OH}	High-level output current		−8		−8		−8	mA
I _{OL}	Low-level output current		16		16		16	mA
f _{clock}	Clock frequency	40		25		16.7		MHz
t _w	Pulse duration	LDCK high or low		10		14		ns
		UNCK high or low		10		14		
		DAF high		10		10		
		RESET low		20		25		
t _{su}	Setup time	D0−D7 before LDCK↑		4		5		ns
		RESET inactive (high) before LDCK↑		5		5		
		Define AF/AE: D0−D8 before DAF↓		5		5		
		Define AF/AE: DAF↓ before RESET↑		7		7		
		Define AF/AE (default): DAF high before RESET↑		5		5		
t _h	Hold time	D0−D7 after LDCK↑		1		2		ns
		Define AF/AE: D0−D8 after DAF↓		0		0		
		Define AF/AE: DAF low after RESET↑		0		0		
		Define AF/AE (default): DAF high after RESET↑		0		0		
T _A	Operating free-air temperature	0	70	0	70	0	70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V_{OH}	$V_{CC} = 4.5\text{ V}$, $I_{OH} = -8\text{ mA}$	2.4			V
V_{OL}	$V_{CC} = 4.5\text{ V}$, $I_{OL} = 16\text{ mA}$			0.5	V
I_I	$V_{CC} = 5.5\text{ V}$, $V_I = V_{CC}$ or 0			±5	μA
I_{OZ}	$V_{CC} = 5.5\text{ V}$, $V_O = V_{CC}$ or 0			±5	μA
I_{CC}^{\ddagger}	$V_I = V_{CC} - 0.2\text{ V}$ or 0			400	μA
ΔI_{CC}^{\ddagger}	$V_{CC} = 5.5\text{ V}$, One input at 3.4 V, Other inputs at V_{CC} or GND			1	mA
C_i	$V_I = 0$, $f = 1\text{ MHz}$		4		pF
C_o	$V_O = 0$, $f = 1\text{ MHz}$		8		pF

† All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ I_{CC} tested with outputs open

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50\text{ pF}$ (see Figures 4 and 5)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	'ACT7802-25			'ACT7802-40		'ACT7802-60		UNIT
			MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
f_{\max}	LDCK or UNCK		40			25		16.7		MHz
t_{pd}	LDCK↑	Any Q	8	20	30	8	35	8	45	ns
t_{pd}	UNCK↑	Any Q	12		30	12	35	12	45	ns
t_{pd}^{\S}	UNCK↑	Any Q		21						ns
t_{PLH}	LDCK↑	EMPTY	4		18	4	20	4	22	ns
t_{PHL}	UNCK↑		2		18	2	20	2	22	
t_{PHL}	RESET↓	EMPTY	2		18	2	20	2	22	ns
t_{PHL}	LDCK↑	FULL	4		18	4	20	4	22	ns
t_{PLH}	UNCK↑	FULL	4		17	4	19	4	21	ns
	RESET↓		2		17	2	19	2	21	
t_{pd}	LDCK↑	AF/AE	2		20	2	22	2	24	ns
	UNCK↑		2		20	2	22	2	24	
t_{PLH}	RESET↓	AF/AE	2		17	2	19	2	21	ns
t_{PLH}	LDCK↑	HF	2		18	2	20	2	22	ns
t_{PHL}	UNCK↑	HF	2		18	2	20	2	22	ns
	RESET↓		2		17	2	19	2	21	
t_{en}	OE	Any Q	2		12	2	14	2	16	ns
t_{dis}	OE	Any Q	2		14	2	16	2	18	ns

† All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

§ This parameter is measured with $C_L = 30\text{ pF}$ (see Figure 1).

operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C_{pd} Power dissipation capacitance per channel	$C_L = 50\text{ pF}$, $f = 5\text{ MHz}$	65	pF

TYPICAL CHARACTERISTICS

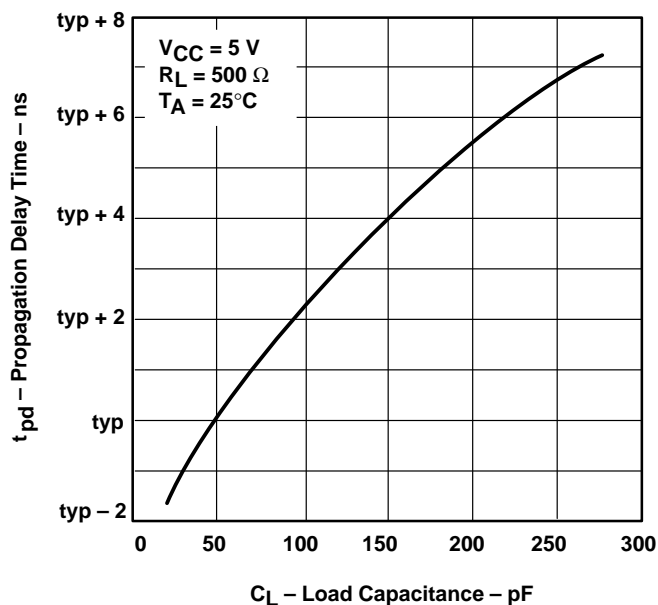
PROPAGATION DELAY TIME
vs
LOAD CAPACITANCE

Figure 1

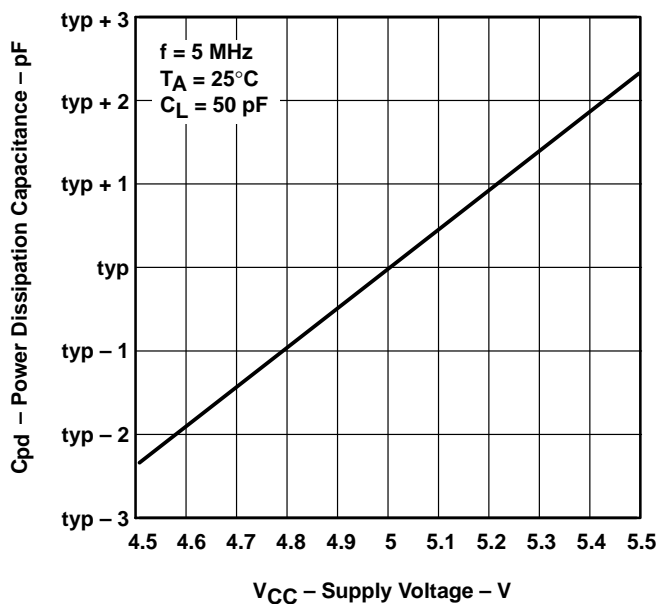
POWER DISSIPATION CAPACITANCE
vs
SUPPLY VOLTAGE

Figure 2

TYPICAL CHARACTERISTICS**calculating power dissipation**

The maximum power dissipation (P_T) of the SN74ACT7802 can be calculated by:

$$P_T = V_{CC} \times [I_{CC} + (N \times \Delta I_{CC} \times dc)] + \Sigma(C_{pd} \times V_{CC}^2 \times f_i) + \Sigma(C_L \times V_{CC}^2 \times f_o)$$

where:

- I_{CC} = power-down I_{CC} maximum
- N = number of inputs driven by a TTL device
- ΔI_{CC} = increase in supply current
- dc = duty cycle of inputs at a TTL high level of 3.4 V
- C_{pd} = power dissipation capacitance
- C_L = output capacitive load
- f_i = data input frequency
- f_o = data output frequency

APPLICATION INFORMATION

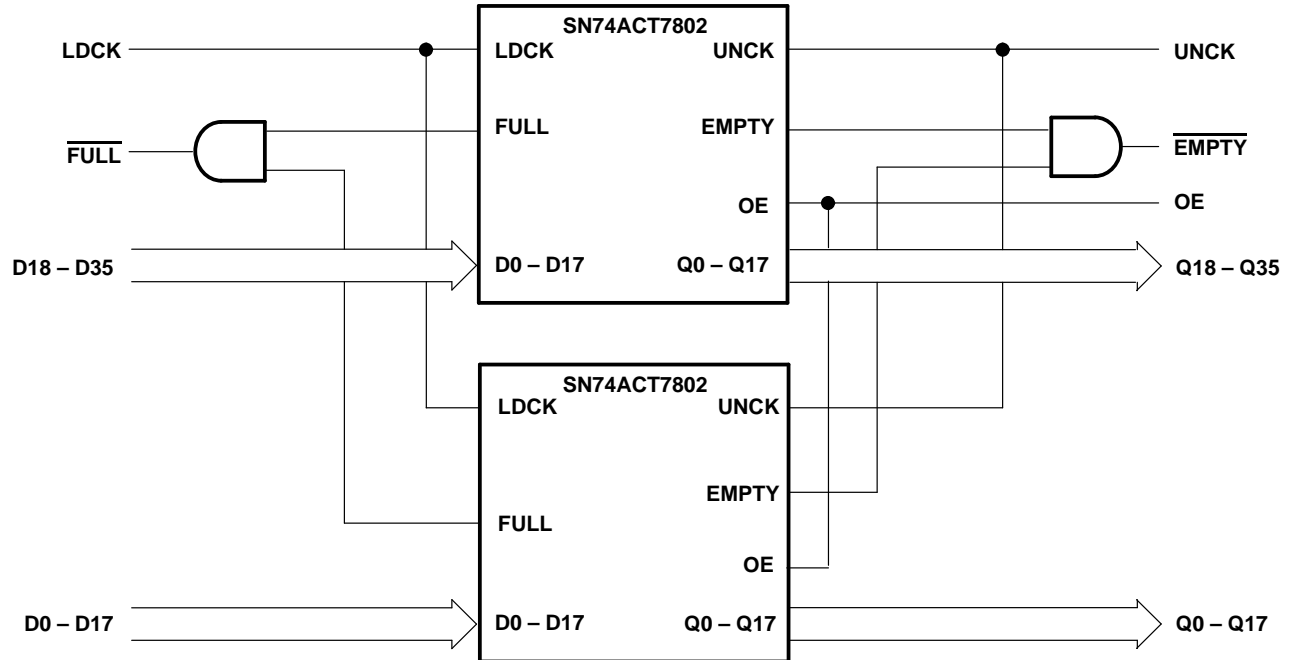
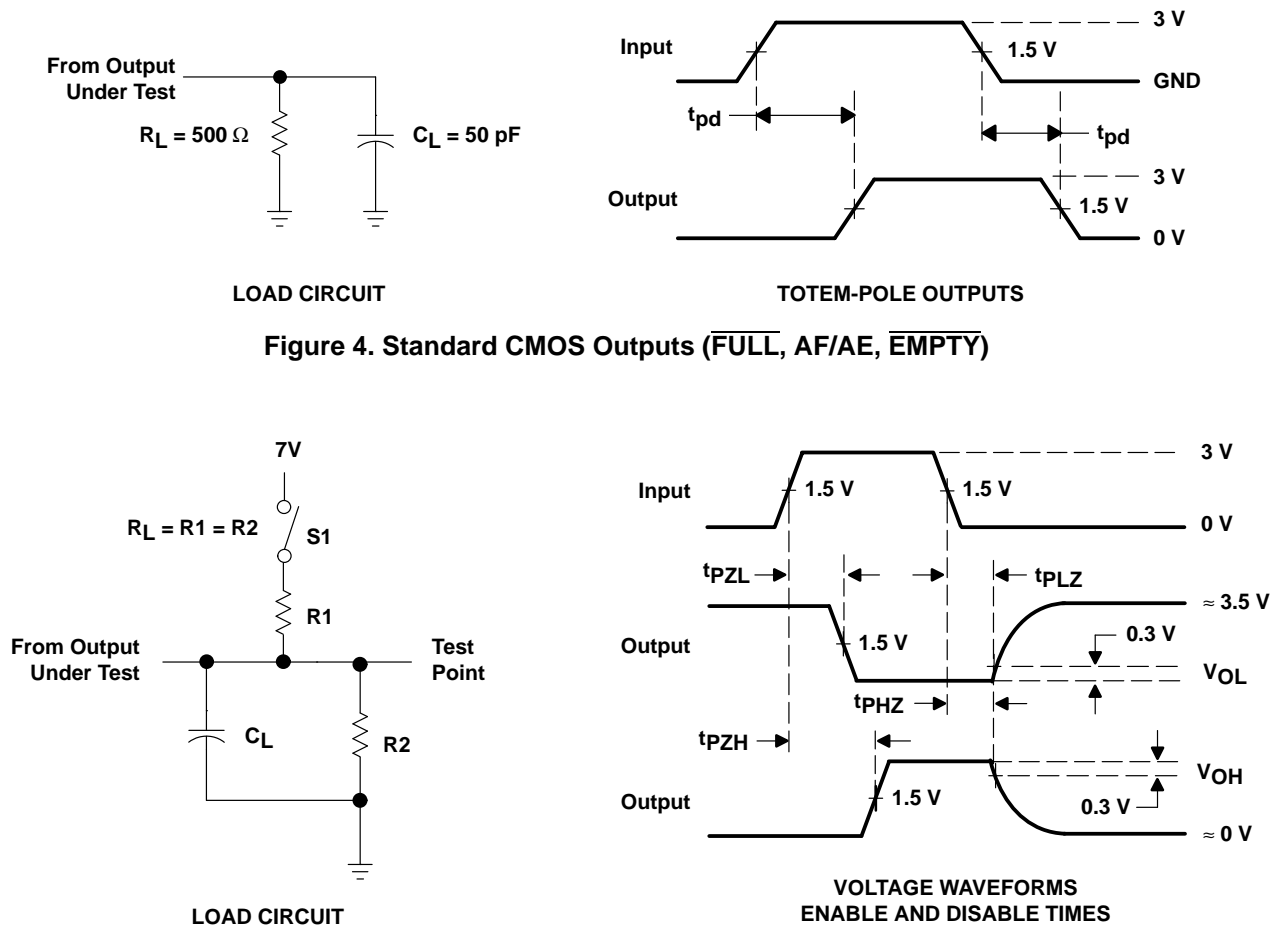


Figure 3. Word-Width Expansion: 1024 Word by 36 Bit

PARAMETER MEASUREMENT INFORMATION



PARAMETER		R1, R2	C_L^\dagger	S1
t_{en}	t_{PZH}	500 Ω	50 pF	Open
	t_{PZL}			Closed
t_{dis}	t_{PHZ}	500 Ω	50 pF	Open
	t_{PLZ}			Closed
t_{pd}		500 Ω	50 pF	Open

[†] Includes probe and test-fixtue capacitance

Figure 5. 3-State Outputs (Any Q)

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